

Docket: 14467.05

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

First Named

Inventor:

John P. Snyder

Appln. No.:

10/796,514

Filing Date:

March 9, 2004

Examiner:

Kim, Su C.

Title:

**Transistor Having High Dielectric Constant Gate** 

**Insulating Layer and Source and Drain Forming** 

Schottky Contact with Substrate

Group Art Unit:

2823

## PETITION FOR EXTENSION OF PERIOD FOR RESPONSE

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450 I hereby certify that this document is being sent via First Class U.S. mail addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 21st day of November, 2005.

(Signature)

Dear Sir:

Pursuant to 37 C.F.R. § 1.136(a), Applicant hereby petitions for an extension of three (3) months from August 20, 2005 to November 20, 2005 within which to respond to the office action dated May 20, 2005. A check in the amount of \$510.00 is enclosed herewith to cover the extension fee.

The Commissioner is hereby authorized to charge any deficiencies or credit any overpayments to Deposit Account No. 04-1420.

11/25/2005 FMETEKI1 00000053 10796514

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510.00 OP

Respectfully submitted,

DORSEY & WHITNEY LLP **Customer Number 25763** 

Date: Nov. 21, 2005

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